



Parameter	Rating	Units
Peak Blocking Voltage	400	V_P
Load Current	140	mA_{rms} / mA_{DC}
On-Resistance (max)	22	Ω

Features

- 5000V_{rms} Input/Output Isolation
- 400V_P Blocking Voltage
- 100% Solid State
- Low Drive Power Requirements (TTL/CMOS Compatible)
- Arc-Free With No Snubbing Circuits
- No EMI/RFI Generation
- Small 4-Pin Package
- Machine Insertable, Wave Solderable

Applications

- Instrumentation
 - Multiplexers
 - Data Acquisition
 - Electronic Switching
 - I/O Subsystems
- Meters (Watt-Hour, Water, Gas)
- Medical Equipment—Patient/Equipment Isolation
- Security
- Aerospace
- Industrial Controls

Description

The CPC1390G is a single-pole normally-open (1-Form-A) Solid State Relay with an enhanced input to output isolation barrier of 5000V_{rms}.

The relay output is constructed with efficient MOSFET switches that use IXYS Integrated Circuits Division's patented OptoMOS architecture. The input, a highly efficient GaAlAs infrared LED, controls the optically coupled output.

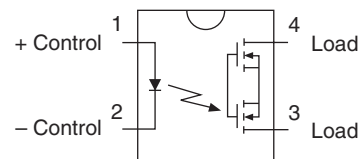
Approvals

- UL Certified Component: File E76270
- CSA Certified Component: Certificate 1172007
- EN/IEC 60950-1 Certified Component:
TUV Certificate B 10 05 49410 006

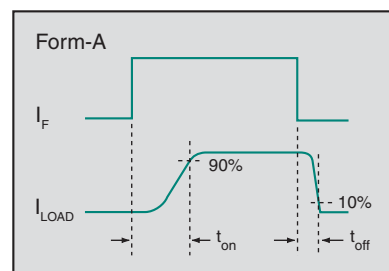
Ordering Information

Part Number	Description
CPC1390G	4-Pin DIP (100/Tube)
CPC1390GV	4-Pin DIP V-Bend (100/Tube)
CPC1390GR	4-Pin Surface Mount (100/Tube)
CPC1390GRTR	4-Pin Surface Mount (1000/Reel)

Pin Configuration



Switching Characteristics
of Normally Open Devices



Absolute Maximum Ratings @ 25°C

Parameter	Ratings	Units
Peak Blocking Voltage	400	V _P
Reverse Input Voltage	5	V
Input Control Current	50	mA
Peak (10ms)	1	A
Input Power Dissipation ¹	100	mW
Total Package Dissipation ²	550	mW
Isolation Voltage, Input to Output, 60 sec.	5000	V _{rms}
ESD Rating, Human Body Model	8	kV
Operational Temperature	-40 to +85	°C
Storage Temperature	-40 to +125	°C

¹ Derate linearly 1.33 mW / °C

² Derate linearly 3.00 mW / °C

Absolute Maximum Ratings are stress ratings. Stresses in excess of these ratings can cause permanent damage to the device. Functional operation of the device at conditions beyond those indicated in the operational sections of this data sheet is not implied.

Electrical Characteristics @ 25°C

Parameters	Conditions	Symbol	Min	Typ	Max	Units
Output Characteristics						
Load Current						
Continuous ¹	-	I _L	-	-	140	mA _{rms} / mA _{DC}
Peak	t=10ms	I _{LPK}	-	-	±400	mA _P
On-Resistance ²	I _F =2mA, I _L =140mA	R _{ON}	-	14	22	Ω
Off-State Leakage Current	V _L =400V _P	I _{LEAK}	-	-	1	μA
Switching Speeds						
Turn-On	I _F =10mA, V _L =10V	t _{on}	-	0.525	1	ms
Turn-Off		t _{off}	-	0.42	1	
Output Capacitance	I _F =0mA, V _L =50V, f=1MHz	C _{OUT}	-	13	-	pF
Input Characteristics						
Input Control Current to Activate ³	I _L =140mA	I _F	-	0.4	2	mA
Input Control Current to Deactivate	-	I _F	0.2	-	-	mA
Input Voltage Drop	I _F =5mA	V _F	0.9	1.2	1.4	V
Reverse Input Current	V _R =5V	I _R	-	-	10	μA
Common Characteristics						
Input to Output Capacitance	-	C _{IO}	-	3	-	pF

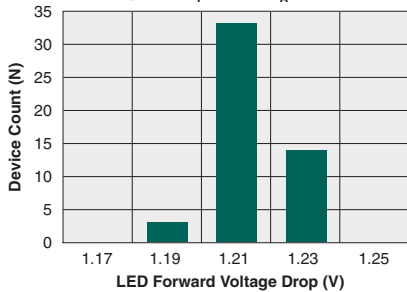
¹ Load current derates linearly from 140mA @ 25°C to 70mA @ 85°C.

² Measurement taken within one second of turn-on time.

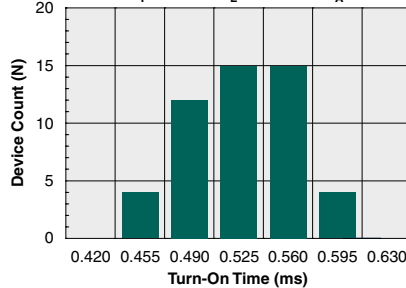
³ For applications requiring high-temperature operation (T_A>60°C), a LED current of 4mA is recommended.

PERFORMANCE DATA*

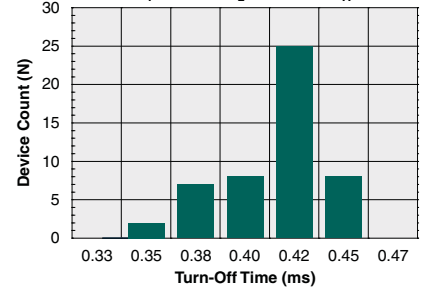
Typical LED Forward Voltage Drop
(N=50, I_F=5mA, T_A=25°C)



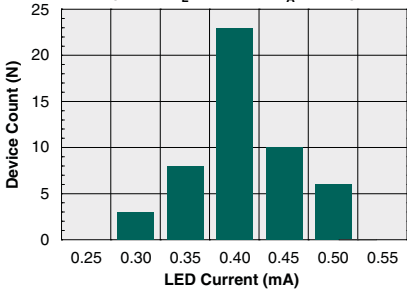
Typical Turn-On Time
(N=50, I_F=10mA, I_L=140mA, T_A=25°C)



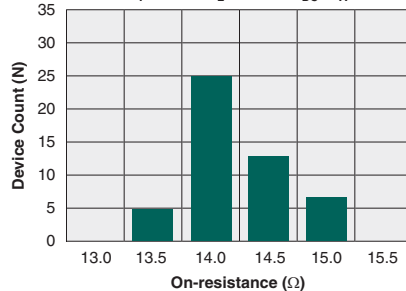
Typical Turn-Off Time
(N=50, I_F=10mA, I_L=140mA, T_A=25°C)



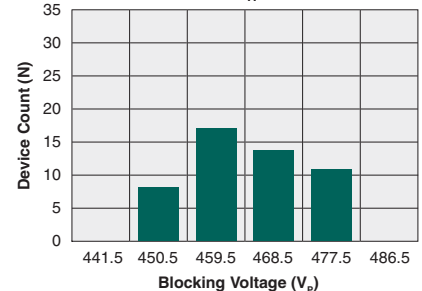
Typical I_F for Switch Operation
(N=50, I_L=140mA, T_A=25°C)



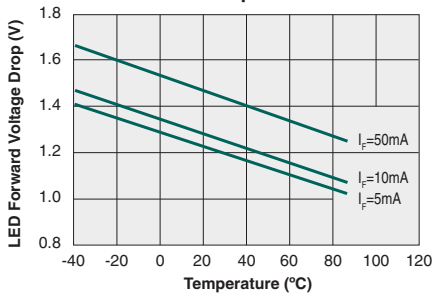
Typical On-Resistance Distribution
(N=50, I_F=2mA, I_L=140mA_{DC}, T_A=25°C)



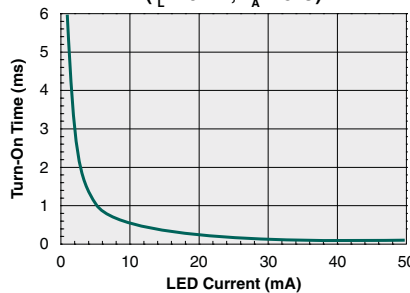
Typical Blocking Voltage Distribution
(N=50, T_A=25°C)



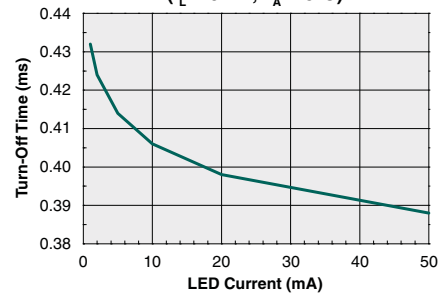
Typical LED Forward Voltage Drop vs. Temperature



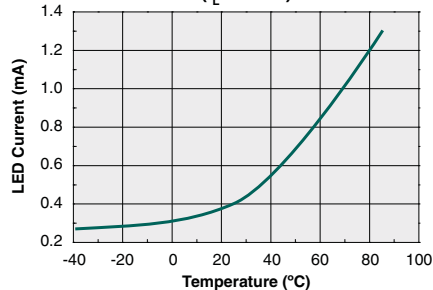
Typical Turn-On Time vs. LED Forward Current
(I_L=70mA, T_A=25°C)



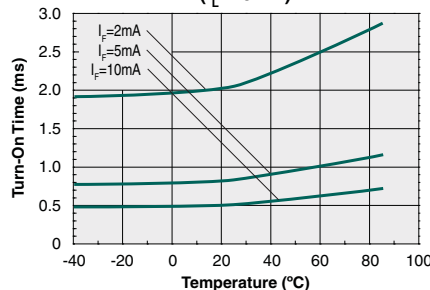
Typical Turn-Off Time vs. LED Forward Current
(I_L=70mA, T_A=25°C)



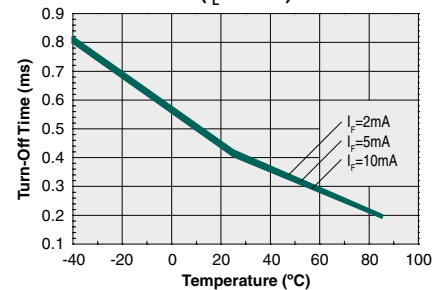
Typical I_F for Switch Operation
(I_L=70mA)



Typical Turn-On Time vs. Temperature
(I_L=70mA)

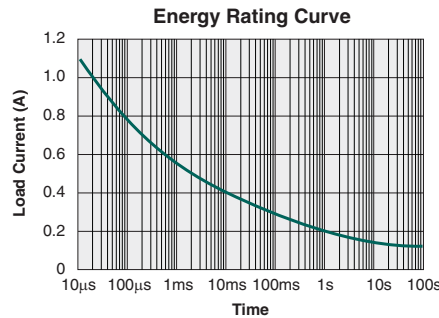
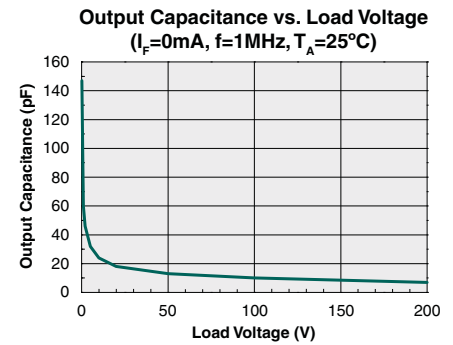
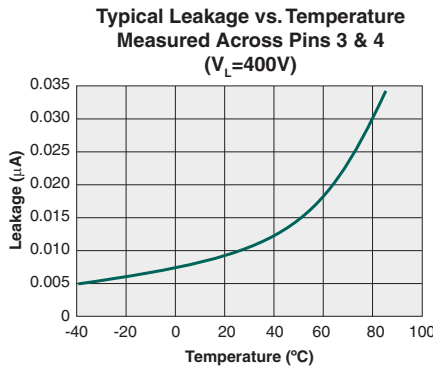
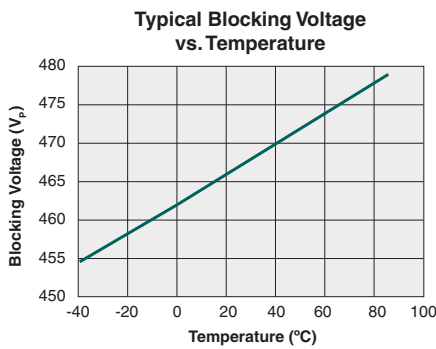
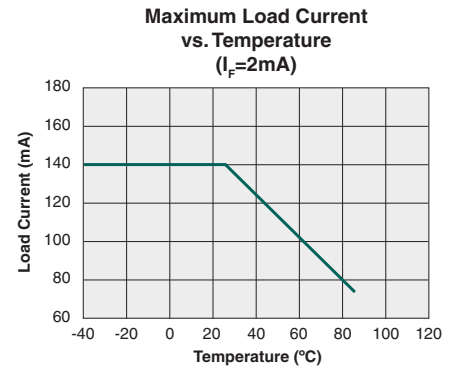
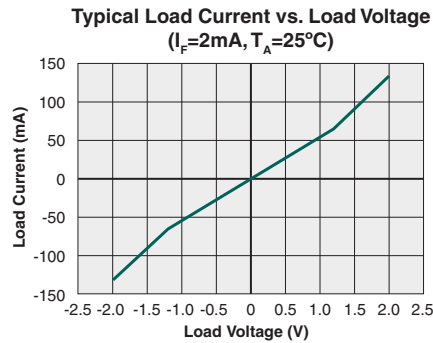
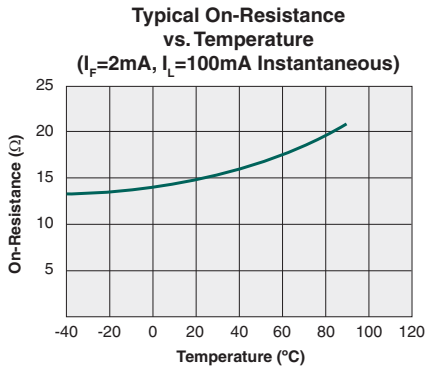


Typical Turn-Off Time vs. Temperature
(I_L=70mA)



*The Performance data shown in the graphs above is typical of device performance. For guaranteed parameters not indicated in the written specifications, please contact our application department.

PERFORMANCE DATA*



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Manufacturing Information

Moisture Sensitivity



All plastic encapsulated semiconductor packages are susceptible to moisture ingress. IXYS Integrated Circuits Division classified all of its plastic encapsulated devices for moisture sensitivity according to the latest version of the joint industry standard, **IPC/JEDEC J-STD-020**, in force at the time of product evaluation. We test all of our products to the maximum conditions set forth in the standard, and guarantee proper operation of our devices when handled according to the limitations and information in that standard as well as to any limitations set forth in the information or standards referenced below.

Failure to adhere to the warnings or limitations as established by the listed specifications could result in reduced product performance, reduction of operable life, and/or reduction of overall reliability.

This product carries a **Moisture Sensitivity Level (MSL) rating** as shown below, and should be handled according to the requirements of the latest version of the joint industry standard **IPC/JEDEC J-STD-033**.

Device	Moisture Sensitivity Level (MSL) Rating
CPC1390G / CPC1390GV / CPC1390GR	MSL 1

ESD Sensitivity



This product is **ESD Sensitive**, and should be handled according to the industry standard **JESD-625**.

Reflow Profile

This product has a maximum body temperature and time rating as shown below. All other guidelines of **J-STD-020** must be observed.

Device	Maximum Temperature x Time
CPC1390G / CPC1390GV / CPC1390GR	250°C for 30 seconds

Board Wash

IXYS Integrated Circuits Division recommends the use of no-clean flux formulations. However, board washing to remove flux residue is acceptable. Since IXYS Integrated Circuits Division employs the use of silicone coating as an optical waveguide in many of its optically isolated products, the use of a short drying bake could be necessary if a wash is used after solder reflow processes. Chlorine- or Fluorine-based solvents or fluxes should not be used. Cleaning methods that employ ultrasonic energy should not be used.

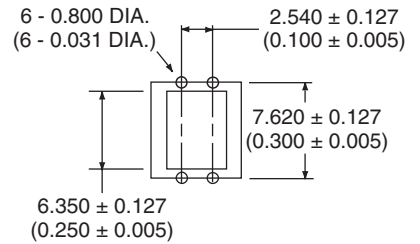


MECHANICAL DIMENSIONS

CPC1390G

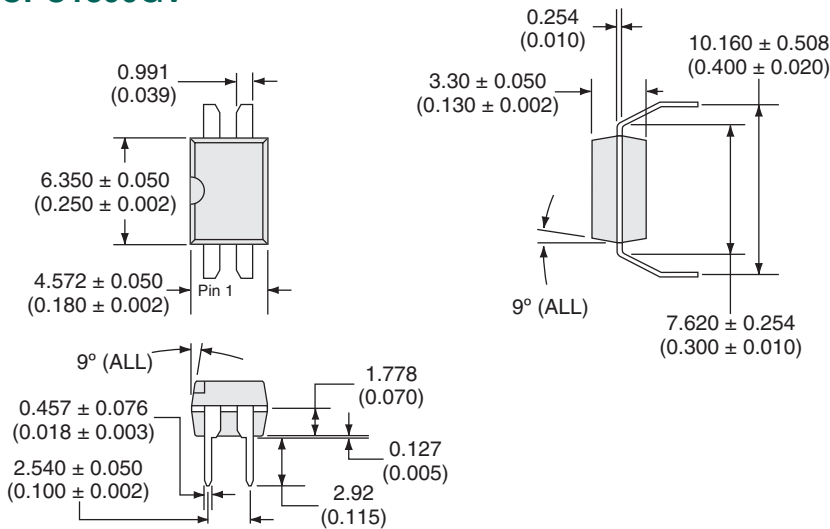


PC Board Pattern (Top View)

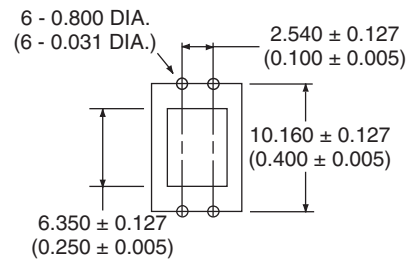


Dimensions
mm
(inches)

CPC1390GV

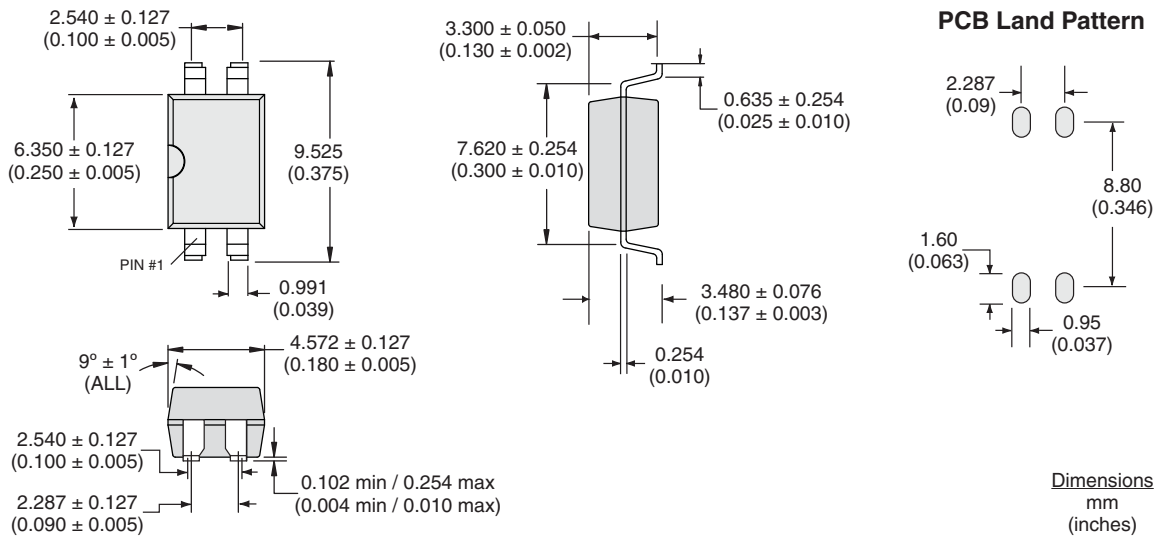


PC Board Pattern (Top View)

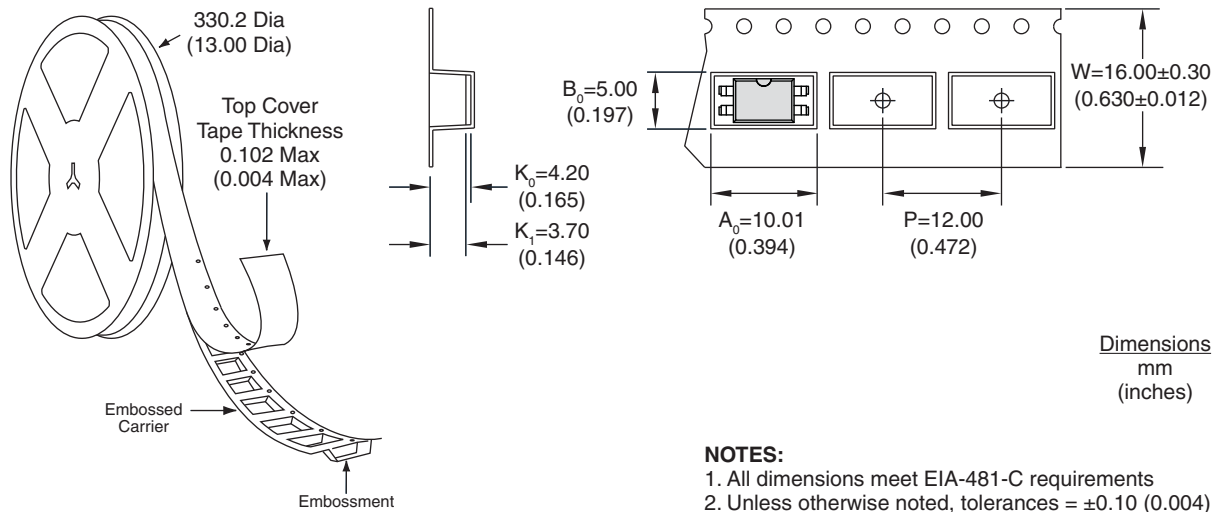


Dimensions
mm
(inches)

CPC1390GR



CPC1390GRTR Tape & Reel



- NOTES:**
1. All dimensions meet EIA-481-C requirements
 2. Unless otherwise noted, tolerances = ± 0.10 (0.004)

For additional information please visit our website at: www.ixysic.com

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- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

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- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

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